# Emmi-X camera C8250-45 series

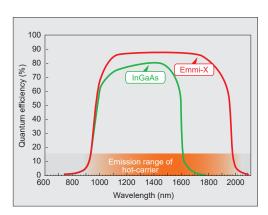
(Near-infrared photo emission camera)

Super high sensitive NIR camera detects emissions from devices driven under 0.5 V.



#### Features

- Higher sensitivity than InGaAs camera.
- Optimized optics design for both macro and micro observation.
- Selectable 3 filters to change cover range of wavelength depending on device design and emission status.



#### Application

 Backside photo emission observation for advanced devices.

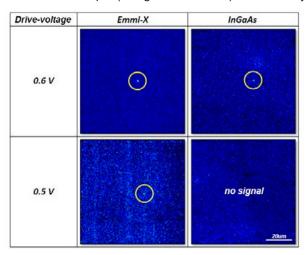


## Failure Analysis Systems Option

#### Case study

- Purpose
- Method
- Result

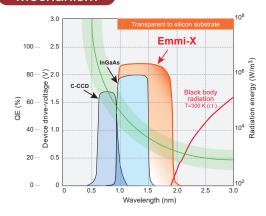
Confirm detectability of photo emission by using an advanced device driven under 0.5 V. Observe a sample (design rule <20 nm) with 20× objective lens, Integration time 300 sec.



Conclusion

Emmi-X camera detected a photo emission from a device running under 0.5 V. It was not possible by an InGaAs camera because the center wavelength of emission from a low-voltage device shifts to longer region, that matches sensitive region of an Emmi-X camera.

### Mechanism



The green curve shows center of photo emission wavelength from semiconductor devices. Following to drive-voltage down, wavelength gets longer and emission intensity gets weaker. Since an Emmi-X camera has higher sensitivity in longer wavelength than InGaAs camera, it is more suitable for photo emission detection for advanced devices than InGaAs camera.

#### Product configuration

Product name	Type number	
Emmi-X camera 1k × 1k LN2 cooling for iPHEMOS®	C8250-45-20	Camera main unit
Emmi-X camera peripherals 1k × 1k LN2 cooling for iPHEMOS®	C8250-45-30	Peripherals

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